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FDG6318PZ

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Dual P-Channel, Digital FET

General Description

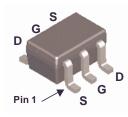
These dual P-Channel logic level enhancement mode MOSFET are produced using Fairchild Semiconductor's especially tailored to minimize on-state resistance. This device has been designed especially for bipolar digital transistors and small signal MOSFETS

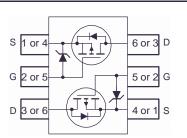
Applications

• Battery management

Features

- -0.5A, -20V. $r_{DS(ON)} = 780m\Omega \text{ (Max)} @ V_{GS} = -4.5 \text{ V}$ $r_{DS(ON)} = 1200m\Omega \text{ (Max)} @ V_{GS} = -2.5 \text{ V}$
- Very low level gate drive requirements allowing direct operation in 3V circuits (V_{GS(TH)} < 1.5V).
- Gate-Source Zener for ESD ruggedness (>1.4kV Human Body Model).
- Compact industry standard SC-70-6 surface mount package.





SC70-6 The pinouts are symmetrical; pin1 and pin 4 are interchangeable.

MOSFET Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{DSS}	Drain to Source Voltage	-20	V
V _{GS}	Gate to Source Voltage	±12	V
	Drain Current		
I _D	Continuous (T _C = 25° C, V _{GS} = - 4.5V)	-0.5	A
	Continuous (T _C = 100° C, V _{GS} = - 2.5V)	-0.3	A
	Pulsed	Figure 4	
P _D	Power dissipation	0.3	W
· D	Derate above 25°C	2.4	mW/ºC
T _J , T _{STG}	Operating and Storage Temperature	-55 to 150	°C
ESD	Electrostatic Discharge Rating MIL-STD-883D Human Body Model (100pF / 1500Ω)	1.4	kV
Therma	I Characteristics		
	Thermal Resistance Junction to Ambient (Note 1)	415	°C/W

		Quantity
.68 FDG6318PZ SC70-6 7" 8	8 mm	3000

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Symbol	Parameter	Test Conditions		Min	Тур	Max	Units
Off Cha	racteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	$I_{D} = -250 \mu A, V_{GS} =$	0V	-20	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{GS} =-16V, V _{GS} =0	V	-	-	-3	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 12V$, $V_{GS} =$	$V_{GS} = \pm 12V$, $V_{GS} = 0V$		-	±10	μΑ
On Cha	racteristics						
V _{GS(TH)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250 \mu A$		-0.65	-0.9	-1.5	V
r _{DS(ON)}	Droin to Course On Registeres	in to Source On Resistance $\frac{I_D = -0.5A, V_{GS} = -4.5V}{I_D = -0.4A, V_{GS} = -2.5V}$		-	580	780	mΩ
·DS(ON)	Drain to Source On Resistance			-	910	1200	
Dynami	c Characteristics						
CISS	Input Capacitance			-	85.4	-	pF
C _{OSS}	Output Capacitance	$V_{DS} = -10V, V_{GS} = 0$ f = 1MHz	$V_{DS} = -10V, V_{GS} = 0V,$		24.9	-	pF
C _{RSS}	Reverse Transfer Capacitance			-	8.83	-	pF
Q _{g(TOT)}	Total Gate Charge at -4.5V	$V_{GS} = 0V$ to -4.5V		-	1.08	1.62	nC
Q _{g(-2.5)}	Total Gate Charge at -2.5V	$V_{GS} = 0V$ to $-2.5V$	V _{DD} = -10V I _D = -0.5A	-	0.67	1.0	nC
Q _{gs}	Gate to Source Gate Charge		$I_{\rm D} = -0.5A$ $I_{\rm a} = 1.0mA$	-	0.21	-	nC
Q _{gd}	Gate to Drain "Miller" Charge				0.33	-	nC
	ng Characteristics (V _{GS} = -4.5V)						
t _{ON}	Turn-On Time			-	-	35	ns
t _{d(ON)}	Turn-On Delay Time			-	10	-	ns
t _r	Rise Time	V _{DD} = -10V, I _D = -0.5	5A	-	13	-	ns
t _{d(OFF)}	Turn-Off Delay Time	$V_{GS} = -4.5V, R_{GS} =$		-	40	-	ns
t _f	Fall Time			-	24	-	ns

Drain-Source Diode Characteristics

Turn-Off Time

V _{SD}	Source to Drain Diode Voltage	I _{SD} = -0.5A	-	-0.9	-1.2	V
t _{rr}	Reverse Recovery Time	I_{SD} = -0.5A, d I_{SD} /dt = 100A/µs	-	-	22	ns
Q _{RR}	Reverse Recovered Charge	I_{SD} = -0.5A, dI_{SD}/dt = 100A/µs	-	-	16	nC

Notes:

t_{OFF}

 R_{eJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the center drain pad. R_{eJC} is guaranteed by design while R_{eCA} is determined by user's board design. R_{eJA} = 415 °C/W when mounted on a 1inch² copper pad.

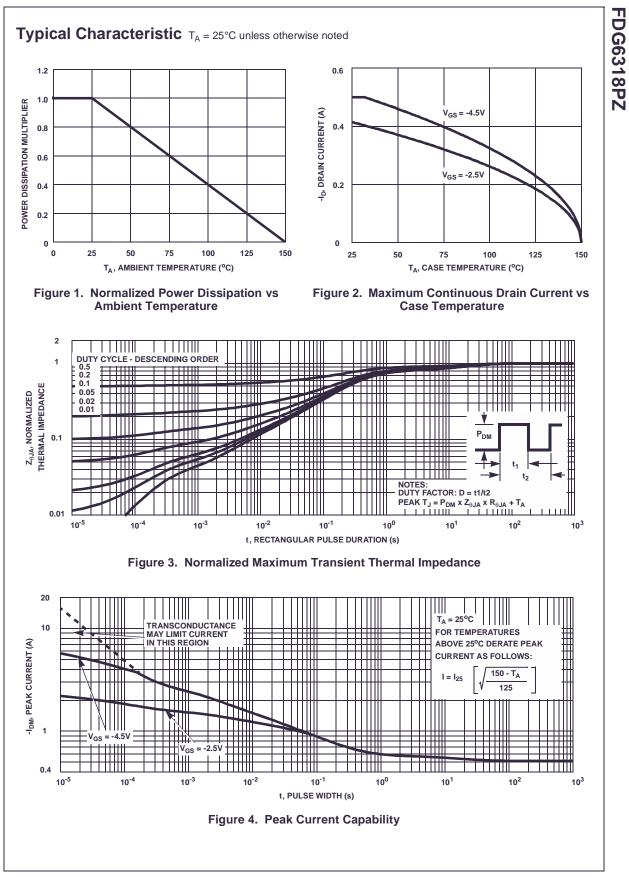
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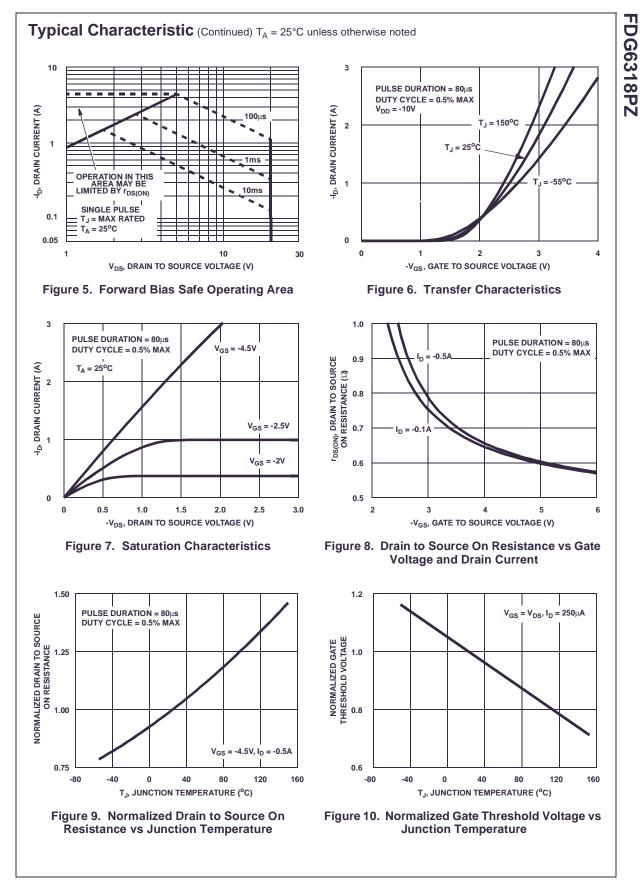
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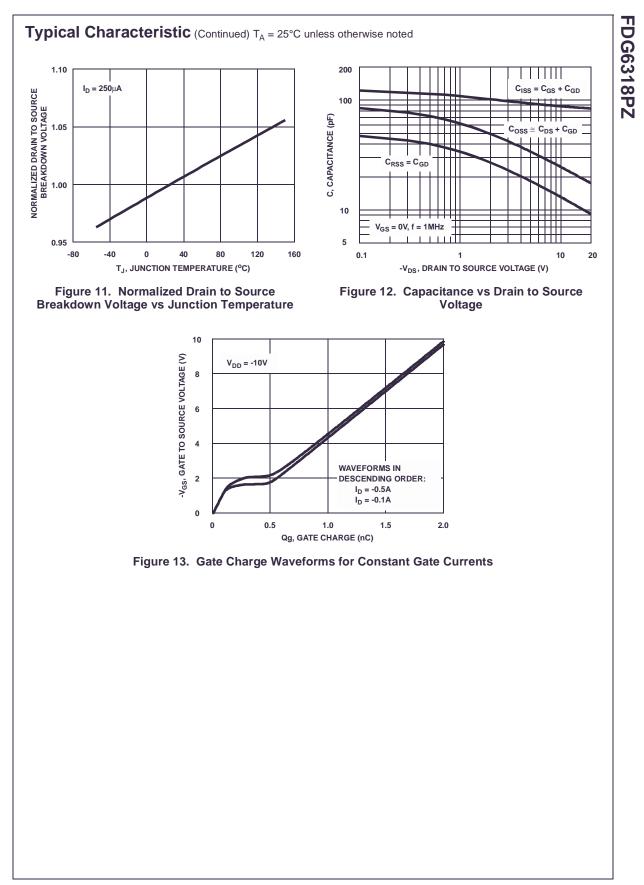
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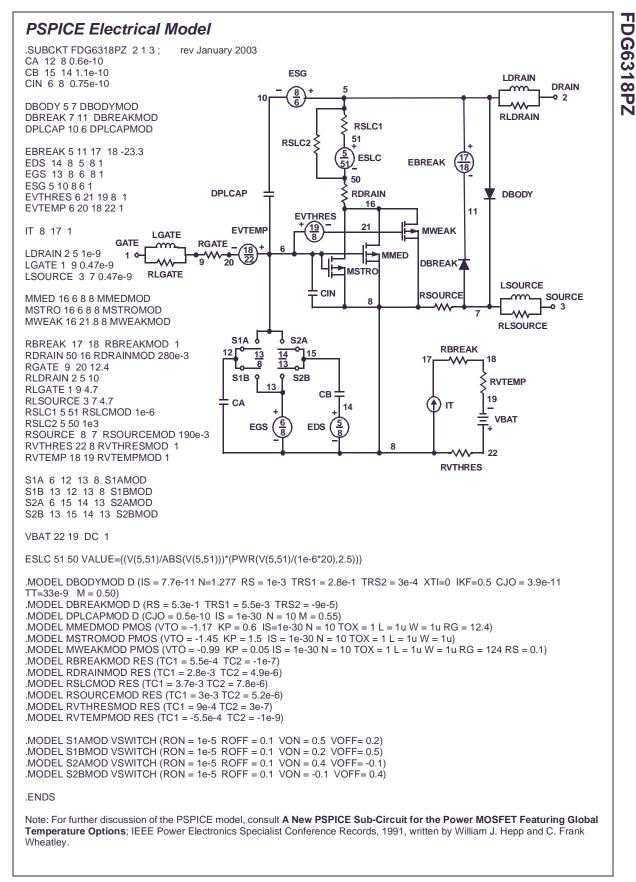




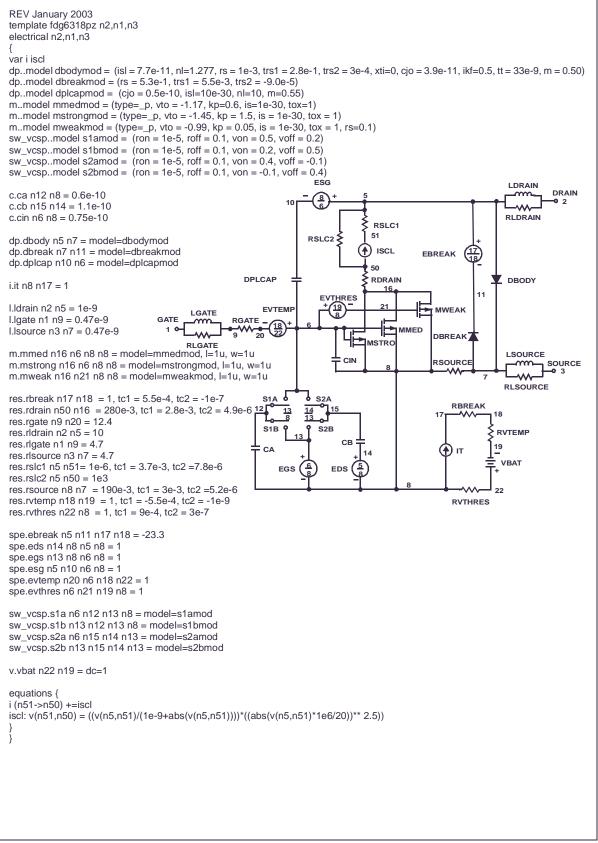
FDG6318PZ Rev. B



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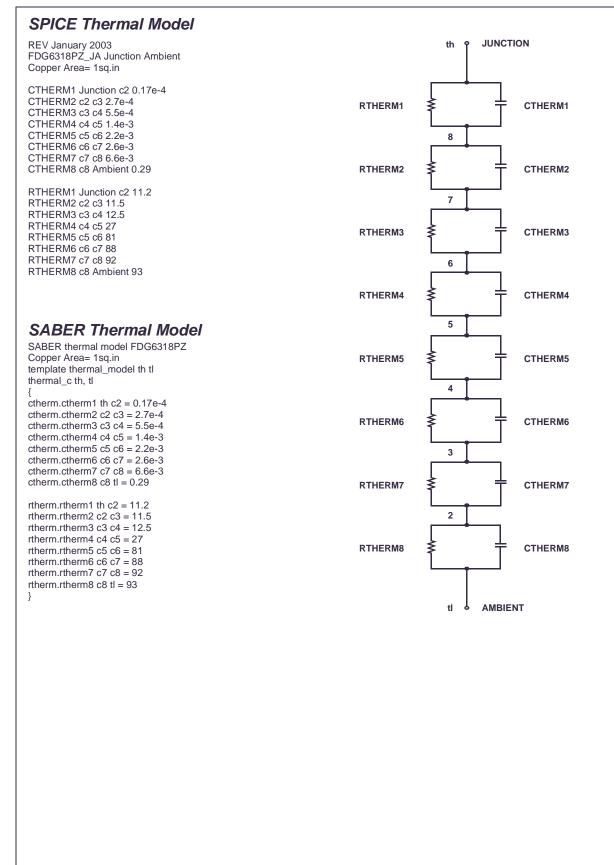


SABER Electrical Model



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DG6318PZ



FDG6318PZ Rev.B

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